

# E11 Lecture 12: Diodes & Transistors

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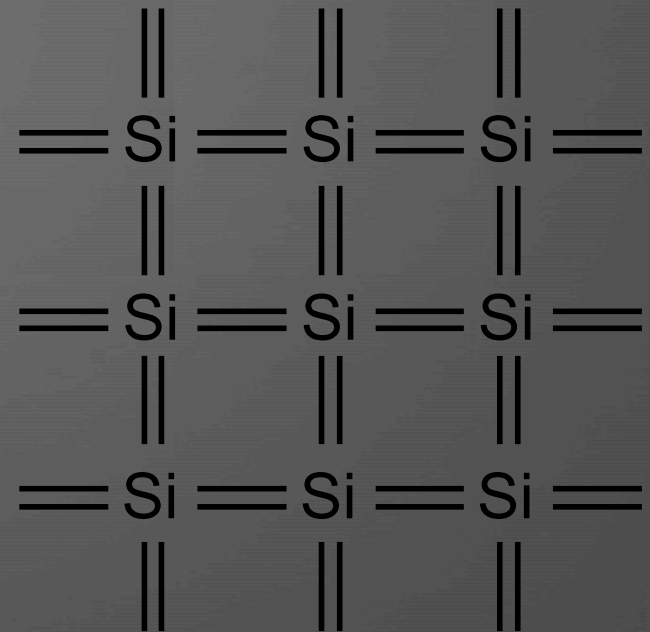
# Outline

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- Semiconductors
- Diodes
- Transistors

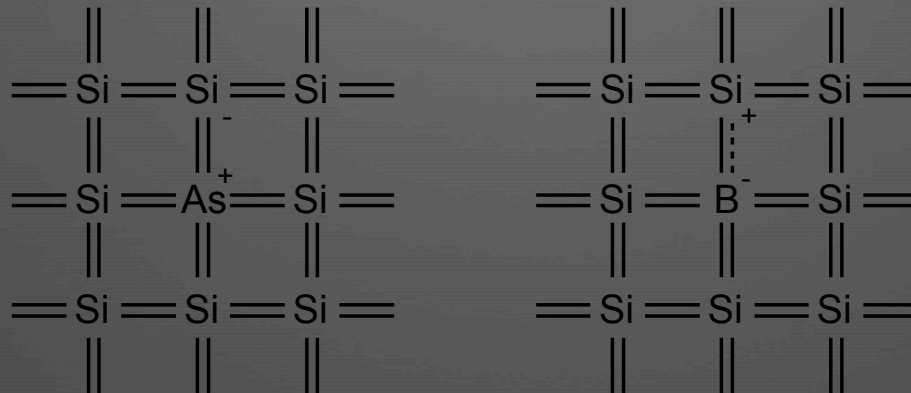
# Semiconductors

- Silicon is a Group IV Material
- Forms tetrahedral crystal with bonds to four neighbors
- Adjustable conductivity



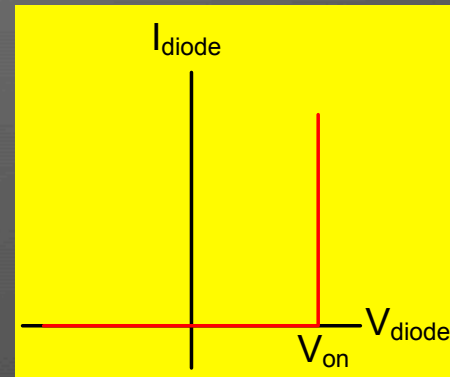
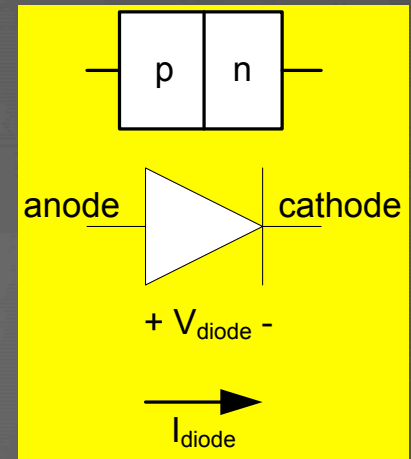
# Dopants

- Silicon is a semiconductor
- Pure silicon has no free carriers and conducts poorly
- Adding dopants increases the conductivity
- Group V: extra electron (n-type)
- Group III: missing electron, called hole (p-type)



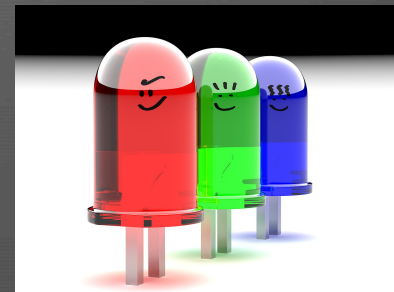
# Diodes

- A p-n junction is called a *diode*
  - p side is called *anode*
  - n side is called *cathode*
- Current only flows from anode to cathode
  - When  $V_{\text{diode}} > V_{\text{on}}$
  - $V_{\text{on}} \approx 0.7 \text{ V}$  for silicon diodes
- Approximate I-V behavior



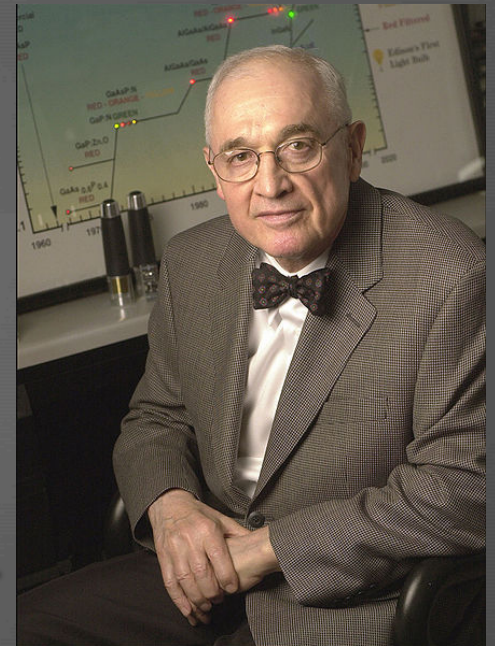
# Light Emitting Diode

- Electron-hole recombination in a diode releases photons
- Wavelength of photons depends on semiconductor's bandgap
- GaAs and related materials glow red, yellow, green, or blue
- $V_{on}$  depends on material, typically  $\sim 1.7$  V
- Typically 5-20 mA gives satisfactory brightness



# Nick Holonyak

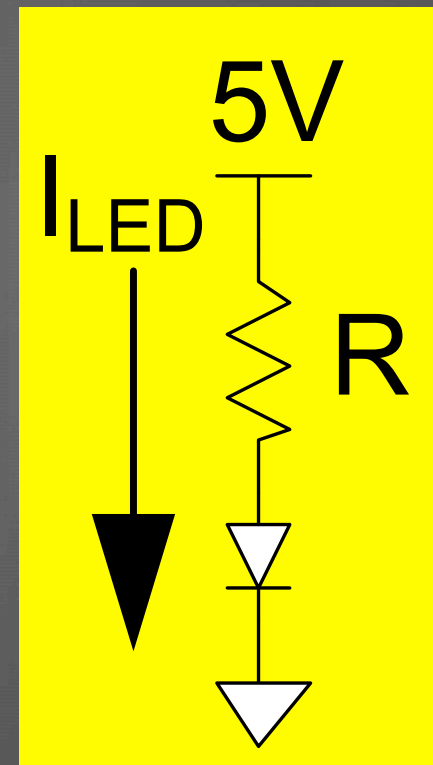
- 1928-
- Invented the first practical visible LED in 1962 while at GE
- EE Prof at University of Illinois
- Also invented laser diode and light dimmer



[en.wikipedia.org/wiki/File:Nick\\_Holonyak\\_Jr.jpg](https://en.wikipedia.org/wiki/File:Nick_Holonyak_Jr.jpg)

# LED Circuit Analysis

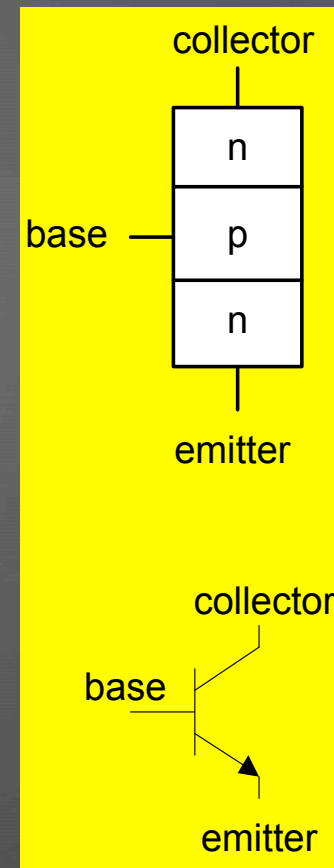
- What value of  $R$  makes  $I_{LED} = 10 \text{ mA}$ ?
- a)  $10 \Omega$
- b)  $100 \Omega$
- c)  $330 \Omega$
- d)  $3 \text{ k}\Omega$





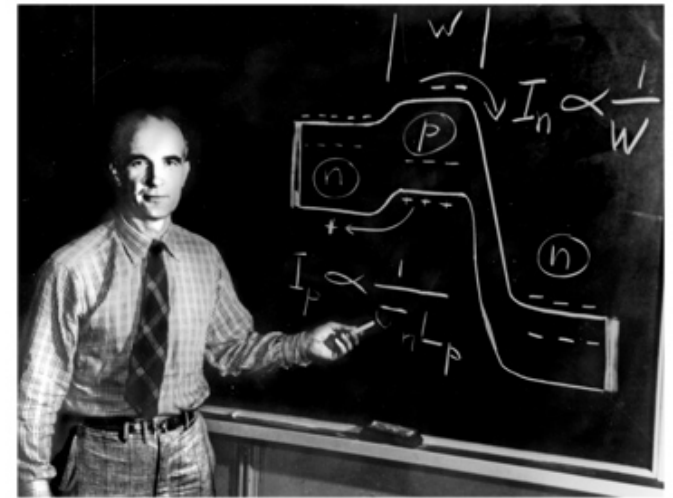
# npn Bipolar Junction Transistor

- Made of two back-to-back diodes
- Behaves as a current-controlled switch
- 3 Terminals
  - Base (control)
  - Emitter (negative switch terminal)
  - Collector (positive switch terminal)



# William Shockley

- 1910-1989
- Son of a mining engineer
- B.S. Caltech, Ph.D. MIT
- Invented BJT in 1948 @ Bell Labs
- Supervised Bardeen & Brattain
  - who invented first transistor in 1947
  - The three received the Nobel Prize in Physics in 1956



computerhistory.org

# npn Transistor Behavior

- Base-to-emitter junction is a diode
- Small base current allows larger collector current to flow
- Three operating regions:
  - Cutoff:
    - no current flows
  - Linear:
    - collector current proportional to base current
  - Saturation:
    - collector current ceases to increase with base current

# Operating Regions

- Three operating regions:

- Cutoff:

- base-emitter diode off
    - no current flows

$$V_{be} < V_{on}$$
$$I_c = 0$$

- Linear:

- base-emitter diode on
    - collector current proportional to base current

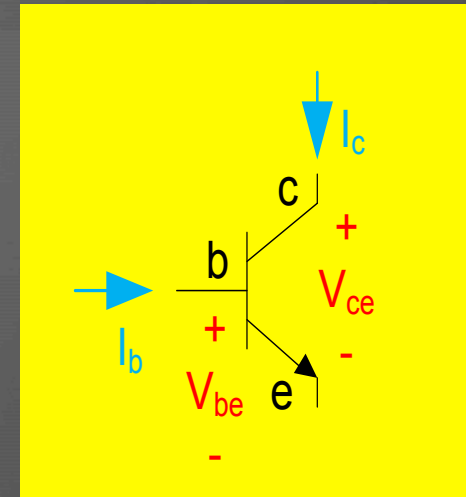
$$V_{be} = V_{on}, V_{ce} > 0$$
$$I_c = \beta I_b$$

$\beta$  typically around 100, but highly variable

- Saturation:

- base-emitter diode on
    - collector current independent of base current

$$V_{be} = V_{on}, V_{ce} \approx 0$$
$$I_c \text{ const}$$

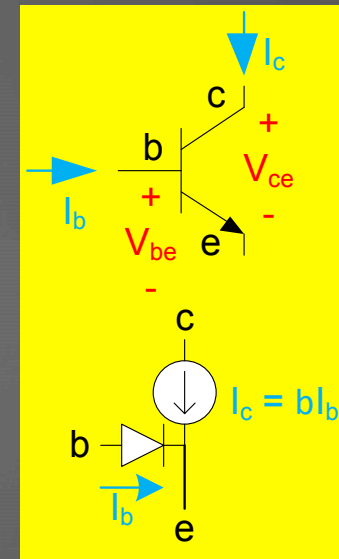


# Linear and Saturation Models

- When  $V_{be} \approx 0.7V$ , transistor turns ON
- If  $V_{ce} > 0$ , transistor behaves as a current amplifier

$$I_c = \beta I_b$$

- If  $V_{ce}$  falls to 0,  $I_c$  ceases to rise with  $I_b$ 
  - Saturation



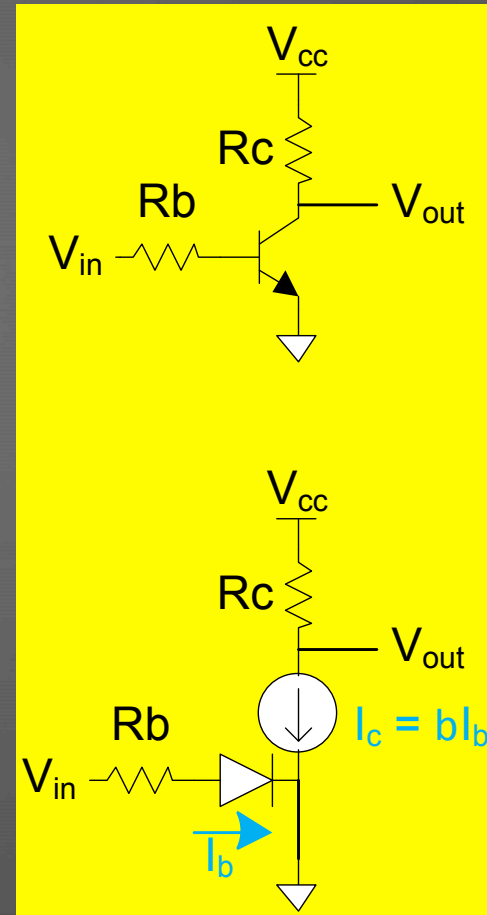
# Transistor Applications

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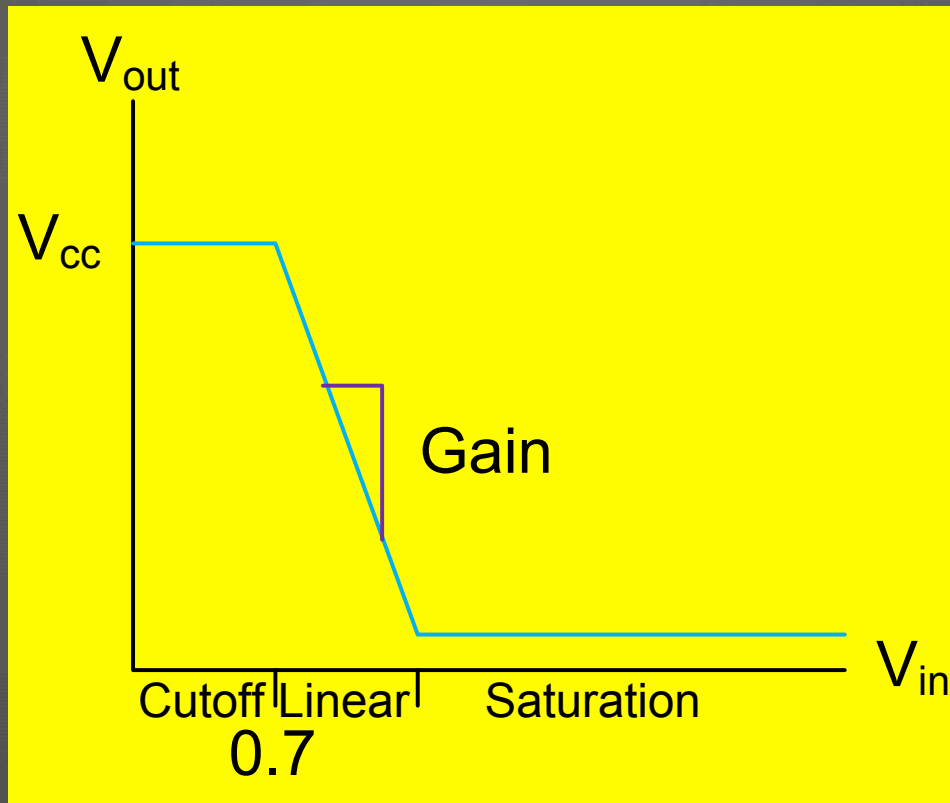
- Amplifiers
- Switches

# Transistor Amplifier

- For  $V_{in} < 0.7$ , Cutoff,  $I_c = 0$ ,  $V_{out} = V_{cc}$
- For  $V_{in} > 0.7$ , linear mode of operation
  - $I_b = (V_{in} - 0.7)/R_b$
  - $I_c = \beta I_b$
  - $V_{out} = V_{DD} - I_c R_c$ 
    - $= V_{DD} - \beta(R_c/R_b)(V_{in} - 0.7)$
  - Gain =  $dV_{out}/dV_{in} = -\beta(R_c/R_b)$
- But  $V_{out}$  never falls below 0
  - Transistor saturates first



# Amplifier Behavior





# Transistor as Switch

- Turn on or off a high-current load
  - Such as the motor
  - Needs more current than digital I/O
- If  $D_2 = 0$ , transistor is cutoff
  - No current flows to load
- If  $D_2 = 1$  (5V), transistor saturates
  - $I_b = (5 - 0.7) / 215 = 20 \text{ mA}$
  - $I_c$  of up to  $\sim 2\text{A}$  flows to load
  - Enough to pull  $x$  down close to 0

